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## 捷多邦,专业PCB打样工厂,24小时加急出货

TS5A22362, TS5A22364

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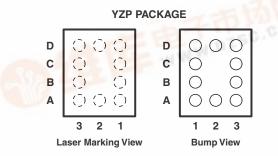
# 0.65-Ω DUAL SPDT ANALOG SWITCHES WITH NEGATIVE SIGNALING CAPABILITY

## **FEATURES**

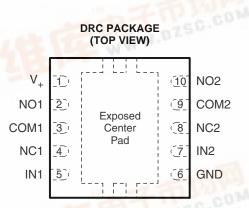
- Specified Break-Before-Make Switching
- Negative Signaling Capability: Maximum Swing From –2.75 V to 2.75 V (V<sub>+</sub> = 2.75 V)
- Internal Shunt Switch Prevents Audible Click-and-Pop When Switching Between Two Sources (TS5A22364)
- Low ON-State Resistance (0.65 Ω Typical)
- Low Charge Injection
- Excellent ON-State Resistance Matching
- 2.3-V to 5.5-V Power Supply (V<sub>+</sub>)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2500-V Human-Body Model (A114-B, Class II)
  - 1500-V Charged-Device Model (C101)
  - 200-V Machine Model (A115-A)

## **APPLICATIONS**

- Cell Phones
- PDAs
- Portable Instrumentation
- Audio Routing

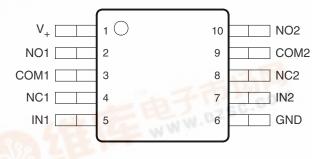


## **DESCRIPTION/ORDERING INFORMATION**



The exposed center pad, if used, must be connected as a secondary GND or left electrically open.

DGS PACKAGE (TOP VIEW)



### YZP PACKAGE TERMINAL ASSIGNMENTS

С	NC1		NCO
			NC2
В	COM1		COM2
Α	NO1	V <sub>+</sub>	NO2
	3	2	1

The TS5A22362 and TS5A22364 are single-pole double-throw (SPDT) analog switches designed to operate from 2.3 V to 5.5 V. The devices feature negative signal capability that allows signals below ground to pass through the switch without distortion. Additionally, the TS5A22364 includes an internal shunt switch, which automatically discharges any capacitance at the NC or NO terminals when they are unconnected to COM. This reduces the audible click/pop noise when switching between two sources. The break-before-make feature prevents signal distortion during the transferring of a signal from one path to another. Low ON-state resistance, excellent channel-to-channel ON-state resistance matching, and minimal total harmonic distortion (THD) performance are ideal for audio applications.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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### ORDERING INFORMATION

T <sub>A</sub>	PACKAGE <sup>(1)(2)</sup>	)	ORDERABLE PART NUMBER	R TOP-SIDE MARKING <sup>(3</sup>		
	NanoFree™ – WCSP (DSBGA)	Topo and real	TS5A22362YZPR	392		
YZ	YZP (Pb-free)	Tape and reel	TS5A22364YZPR	382		
		Tana and soal	TS5A22362DGSR	39R		
–40°C to 85°C	MSOP (VSSOP) – DGS	Tape and reel	TS5A22364DGSR	38R		
	2011 000	Tana and so d	TS5A22362DRCR	ZVG		
	SON – DRC	Tape and reel	TS5A22364DRCR	ZVF		

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

(3) YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

V <sub>+</sub> = 2.7 V, T <sub>A</sub> = 25°C	
Configuration	2:1 Multiplexer/Demultiplexer (2 × SPDT)
Number of channels	2
ON-state resistance (ron)	0.65 Ω
ON-state resistance match ( $\Delta r_{on}$ )	0.023 Ω
ON-state resistance flatness (r <sub>on(flat)</sub> )	0.18 Ω
Turn-on/turn-off time (t <sub>ON</sub> /t <sub>OFF</sub> )	80 ns/70 ns
Break-before-make time (t <sub>BBM</sub> )	7 ns
Charge injection (Q <sub>C</sub> )	150 pC
Bandwidth (BW)	17 MHz
OFF isolation (O <sub>ISO</sub> )	–66 dB at 100 kHz
Crosstalk (X <sub>TALK</sub> )	–75 dB at 100 kHz
Total harmonic distortion (THD)	0.01%
Leakage current (I <sub>NO(OFF)</sub> , I <sub>NC(OFF)</sub> )	TBD nA
Package options	10-pin WCSP (YZP), 10-pin VSSOP (DGS), and 10-pin SON (DRC)

### SUMMARY OF CHARACTERISTICS

#### **FUNCTION TABLE**

IN	NC TO COM, COM TO NC	NO TO COM, COM TO NO				
L	ON	OFF				
Н	OFF	ON				



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## APPLICATION BLOCK DIAGRAMS

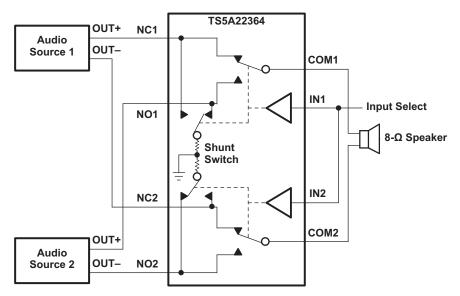
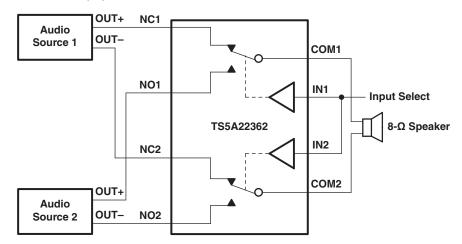


Figure 1. TS5A22364 Application Block Diagram

### Shunt Switch (TS5A22364)

The 50- $\Omega$  shunt switches on the TS5A22364 automatically discharge any capacitance at the NC or NO terminals when they are unconnected to COM. This reduces audible click-and-pop sounds that occur when switching between audio sources. Audible clicks and pops are caused when a step DC voltage is switched into the speaker. By automatically discharging the side that is not connected, any residual DC voltage is removed, thereby reducing the clicks and pops.





### **Negative Signaling Capacity**

The TS5A22362 and TS5A22364 dual SPDT switches feature negative signal capability that allows signals below ground to pass through without distortion. These analog switches operate from a single +2.3-V to +5.5-V supply. The input/output signal swing of the device is dependent of the supply voltage V<sub>+</sub>: the devices pass signals as high as V<sub>+</sub> and as low as V<sub>+</sub> – 5.5 V, including signals below ground with minimal distortion.

Table 1 shows the input/output signal swing the user can get with different supply voltages.



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Tal	ble 1. INPUT/OUTPUT SIGNAL	SWING
SUPPLY VOLTAGE, V+	$\begin{array}{l} \text{MINIMUM} \\ (\text{V}_{\text{NC}},  \text{V}_{\text{NO}},  \text{V}_{\text{COM}}) = \text{V}_{+} - 5.5 \end{array}$	$\begin{array}{c} \text{MAXIMUM} \\ (\text{V}_{\text{NC}}, \text{ V}_{\text{NO}}, \text{ V}_{\text{COM}}) = \text{V}_{+} \end{array}$
5.5 V	0 V	5.5 V
4.2 V	–1.3 V	4.2 V
3.3 V	–2.2 V	3.3 V
3 V	–2.5 V	3 V
2.5 V	–3 V	2.5 V

## ABSOLUTE MINIMUM AND MAXIMUM RATINGS<sup>(1)(2)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V+	Supply voltage range <sup>(3)</sup>		-0.5	6	V
V <sub>NC</sub> V <sub>NO</sub> V <sub>COM</sub>	Analog voltage range <sup>(3)(4)(5)</sup>		V <sub>+</sub> – 6	V <sub>+</sub> + 0.5	V
I <sub>I/OK</sub>	Analog port diode current	$V_{NC}$ , $V_{NO}$ , $V_{COM} < 0$ or $V_{NC}$ , $V_{NO}$ , $V_{COM} > V_{+}$	-50	50	mA
I <sub>NC</sub>	ON-state switch current		-150	150	
I <sub>NO</sub> I <sub>COM</sub>	ON-state peak switch current <sup>(6)</sup>	$V_{NC}$ , $V_{NO}$ , $V_{COM} = 0$ to $V_{+}$	-300	300	mA
VI	Digital input voltage range		-0.5	6.5	V
I <sub>IK</sub>	Digital input clamp current <sup>(3)(4)</sup>	V <sub>1</sub> < 0	-50	50	mA
I <sub>+</sub> I <sub>GND</sub>	Continuous current through V <sub>+</sub> or GND		-100	100	mA
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

(2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(3) All voltages are with respect to ground, unless otherwise specified.

(4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(5) This value is limited to 5.5 V maximum.

(6) Pulse at 1-ms duration <10% duty cycle

## THERMAL IMPEDANCE RATINGS

				UNIT
		DGS package	56.5	
$\theta_{JA}$	Package thermal impedance <sup>(1)</sup>	DRC package	165.36	°C/W
		YZP package	93	

(1) The package thermal impedance is calculated in accordance with JESD 51-7.

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### ELECTRICAL CHARACTERISTICS FOR 2.5-V SUPPLY<sup>(1)</sup>

 $V_{+}$  = 2.3 V to 2.7 V,  $T_{A}$  = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST COND	ITIONS	TA	۷.	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V <sub>COM</sub> , V <sub>NO</sub> , V <sub>NC</sub>					V <sub>+</sub> – 5.5		V+	V
ON-state		$V_{\rm NC} \text{ or } V_{\rm NO} = V_+, 1.5 \text{ V},$	COM to NO or NC,	25°C			0.65	0.94	
resistance	r <sub>on</sub>	V <sub>+</sub> – 5.5 V I <sub>COM</sub> = –100 mA,	See Figure 16	Full	2.7 V			1.04	Ω
ON-state				25°C			0.023	0.11	
resistance match between channels	∆r <sub>on</sub>	$V_{NC}$ or $V_{NO}$ = 1.5 V, $I_{COM}$ = -100 mA,	COM to NO or NC, See Figure 16	Full	2.7 V			0.15	Ω
ON-state		$V_{NC} \text{ or } V_{NO} = V_{+}, 1.5 \text{ V},$	COM to NO or NC,	25°C			0.18	0.46	
resistance flatness	r <sub>on(flat)</sub>	$V_{+} - 5.5 V$ I <sub>COM</sub> = -100 mA,	See Figure 16	Full	2.7 V			0.5	Ω
Shunt switch resistance (TS5A22364 only)	r <sub>SH</sub>	$I_{NO}$ or $I_{NC}$ = 10 mA		Full	2.7 V		25	50	Ω
		$V_{\rm NC}$ = 2.25 V, V <sub>+</sub> – 5.5 V		25°C		-50		50	
NC, NO OFF leakage current (TS5A22362 Only)	I <sub>NC(OFF)</sub> , I <sub>NO(OFF)</sub>	$\begin{array}{l} V_{COM} = V_{+} - 5.5 \ V, \ 2.25 \ V \\ V_{NO} = Open \\ COM \ to \ NO \\ or \\ V_{NO} = 2.25 \ V, \ V_{+} - 5.5 \ V, \\ V_{COM} = V_{+} - 5.5 \ V, \ 2.25 \ V \\ V_{NC} = Open \\ COM \ to \ NC \end{array}$	See Figure 17	Full	2.7	-375		375	nA
COM		$V_{NC}$ and $V_{NO}$ = Open,		25°C		-50		50	
ON leakage current	I <sub>COM(ON)</sub>	$V_{COM} = V_+, V_+ - 5.5 V,$	See Figure 18	Full	2.7 V	-375		375	nA
<b>Digital Control In</b>	outs (IN) <sup>(2)</sup>								
Input logic high	VIH			Full		1.4		5.5	V
Input logic low	VIL			Full				0.6	V
Input leakage current	I <sub>IH</sub> , I <sub>IL</sub>	$V_{IN} = V_+ \text{ or } 0$		25°C Full	2.7 V	-250 -250		250 250	nA

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

 (2) All unused digital inputs of the device must be held at V<sub>+</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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## **ELECTRICAL CHARACTERISTICS FOR 2.5-V SUPPLY (continued)**

 $V_{\star}$  = 2.3 V to 2.7 V,  $T_{A}$  = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST COND	ITIONS	TA	۷.	MIN	TYP	MAX	UNIT
Dynamic									
			0 05 - 5	25°C	2.5 V		44	80	
Turn-on time	t <sub>ON</sub>		C <sub>L</sub> = 35 pF, See Figure 20	Full	2.3 V to 2.7 V			80	ns
			0 25 55	25°C	2.5 V		22	70	
Turn-off time	t <sub>OFF</sub>	$V_{COM} = V_+, \\ R_L = 300 \ \Omega,$	C <sub>L</sub> = 35 pF, See Figure 20	Full	2.3 V to 2.7 V			70	ns
Break-before- make time	t <sub>BBM</sub>	See Figure 21 for TS5A22 See Figure 22 for TS5A22		25°C	2.5 V	1	1 7		ns
Charge injection	Q <sub>C</sub>	$V_{GEN} = 0,$ $R_{GEN} = 0,$	C <sub>L</sub> = 1 nF, See Figure 26	25°C	2.5 V		150		рС
NC, NO OFF capacitance (TS5A22362 only)	C <sub>NC(OFF)</sub> , C <sub>NO(OFF)</sub>	$V_{NC}$ or $V_{NO} = V_{+}$ or GND,	See Figure 19	25°C	2.5 V		70		pF
NC, NO, COM ON capacitance	C <sub>COM(ON)</sub>	$V_{COM} = V_+ \text{ or GND},$ Switch ON, f = 10 MHz	See Figure 19	25°C	2.5 V		370		pF
Digital input capacitance	CI	$V_I = V_+ \text{ or } GND$	See Figure 19	25°C	2.5 V		2.6		pF
Bandwidth	BW	$R_L = 50 \Omega, -3 dB$	See Figure 21	25°C	2.5 V		17		MHz
OFF isolation	O <sub>ISO</sub>	R <sub>L</sub> = 50 Ω	f = 100 kHz, See Figure 24	25°C	2.5 V		-66		dB
Crosstalk	X <sub>TALK</sub>	R <sub>L</sub> = 50 Ω	f = 100 kHz, See Figure 25	25°C	2.5 V		-75		dB
Total harmonic distortion	THD	$ \begin{array}{l} R_{L} = 600 \ \Omega, \\ C_{L} = 15 \ pF, \end{array} $	f = 20 Hz to 20 kHz, See Figure 27	25°C	2.5 V		0.01		%
Supply									
Positive supply current	I+	V <sub>I</sub> = V+ or GND		25°C Full	2.7 V		0.2	1.1 1.3	μA
Positive supply current	I+	V <sub>I</sub> = V+ - 5.5 V		Full	2.7 V			3.3	μΑ

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### ELECTRICAL CHARACTERISTICS FOR 3.3-V SUPPLY<sup>(1)</sup>

 $V_{\star}$  = 3 V to 3.6 V,  $T_{A}$  = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CON	DITIONS	T <sub>A</sub>	٧.	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V <sub>COM</sub> , V <sub>NO</sub> , V <sub>NC</sub>					V <sub>+</sub> – 5.5		V+	V
		$V_{NC}$ or $V_{NO} \le V_+$ ,	COM to NO or	25°C			0.61	0.87	
ON-state resistance	r <sub>on</sub>	1.5 V, V <sub>+</sub> – 5.5 V, I <sub>COM</sub> = –100 mA,	NC, See Figure 16	Full	3 V			0.97	Ω
ON-state			COM to NO or	25°C			0.024	0.13	
resistance match between channels	∆r <sub>on</sub>	$V_{NC}$ or $V_{NO} = 1.5$ V, $I_{COM} = -100$ mA,	NC, See Figure 16	Full	3 V			0.13	Ω
ON-state		$V_{NC}$ or $V_{NO} \le V_+$ ,	COM to NO or	25°C			0.12	0.46	
resistance flatness	r <sub>on(flat)</sub>	1.5 V, V <sub>+</sub> – 5.5 V, I <sub>COM</sub> = –100 mA,	NC, See Figure 16	Full	3 V			0.5	Ω
Shunt switch resistance (TS5A22364 only)	r <sub>SH</sub>	$I_{NO}$ or $I_{NC}$ = 10 mA		Full	3 V		25	37	Ω
		$V_{\rm NC} = 3  \rm V,  V_{+} - 5.5  \rm V$		25°C		-50		50	
NC, NO OFF leakage current (TS5A22362 only)	I <sub>NC(OFF)</sub> , I <sub>NO(OFF)</sub>	$\begin{array}{l} V_{COM} = V_{+} - 5.5 \ V, \ 3 \ V \\ V_{NO} = Open \\ COM \ to \ NO \\ or \\ V_{NO} = 3 \ V, \ V_{+} - 5.5 \ V, \\ V_{COM} = V_{+} - 5.5 \ V, \ 3 \ V \\ V_{NC} = Open \\ COM \ to \ NC \end{array}$	See Figure 17	Full	3.6 V	-375		375	nA
COM		$V_{NC}$ and $V_{NO}$ = Open,	COM to NO or	25°C		-50		50	_
ON leakage current	I <sub>COM(ON)</sub>	$V_{\rm COM} = V_+, V_+ - 5.5 V,$	NC, See Figure 18	Full	3.6 V	-375		375	nA
Digital Control Inp	outs (IN) <sup>(2)</sup>	1		1	1	1			
Input logic high	V <sub>IH</sub>			Full		1.4		5.5	V
Input logic low	V <sub>IL</sub>			Full				0.8	V
Input leakage	ו <sub>וו</sub> , ו <sub>וב</sub>	$V_{IN} = V_{+}$ or 0		25°C	3.6 V	-250		250	nA
current	11H, 11L			Full	5.0 v	-250		250	114

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(2) All unused digital inputs of the device must be held at V<sub>+</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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## **ELECTRICAL CHARACTERISTICS FOR 3.3-V SUPPLY (continued)**

 $V_{\star}$  = 3 V to 3.6 V,  $T_{A}$  = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CO	NDITIONS	T <sub>A</sub>	٧.	MIN	TYP	MAX	UNIT
Dynamic								1	
		., .,	0 05 5	25°C	3.3 V		34	80	
Turn-on time	t <sub>ON</sub>		C <sub>L</sub> = 35 pF, See Figure 20	Full	3 V to 3.6 V			80	ns
			0 25 55	25°C	3.3 V		19	70	
Turn-off time	t <sub>OFF</sub>	$V_{COM} = V_+, \\ R_L = 300 \ \Omega,$	C <sub>L</sub> = 35 pF, See Figure 20	Full	3 V to 3.6 V			70	ns
Break-before- make time	t <sub>BBM</sub>	See Figure 21 for TS5A22362 See Figure 22 for TS5A22364		25°C	3.3 V	1	7		ns
Charge injection	Q <sub>C</sub>	$V_{GEN} = 0,$ $R_{GEN} = 0,$	C <sub>L</sub> = 1 nF, See Figure 26	25°C	3.3 V		150		рС
NC, NO OFF capacitance (TS5A22362 only)	C <sub>NC(OFF)</sub> , C <sub>NO(OFF)</sub>	$V_{NC}$ or $V_{NO} = V_+$ or $V_+ - 5.5 V_+$	See Figure 19	25°C	3.3 V		70		pF
NC, NO, COM ON capacitance	C <sub>COM(ON)</sub>	$V_{COM} = V_+ \text{ or GND},$ f = 10 MHz	See Figure 19	25°C	3.3 V		370		pF
Digital input capacitance	Cı	$V_I = V_+ \text{ or } GND$	See Figure 19	25°C	3.3 V		2.6		pF
Bandwidth	BW	$R_L = 50 \ \Omega, -3 \ dB$	Switch ON, See Figure 21	25°C	3.3 V		17.5		MHz
OFF isolation	O <sub>ISO</sub>	$R_L = 50 \Omega$ ,	f = 100 kHz, See <mark>Figure 24</mark>	25°C	3.3 V		-68		dB
Crosstalk	X <sub>TALK</sub>	$R_L = 50 \Omega$ ,	f = 100 kHz, See <mark>Figure 25</mark>	25°C	3.3 V		-76		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 15 \text{ pF},$	f = 20 Hz to 20 kHz, See Figure 27	25°C	3.3 V		0.008		%
Supply									
Desition		$V_1 = V_+ \text{ or } GND$		25°C	3.6 V		0.1	1.2	μA
Positive supply current	current I <sub>+</sub>		עווט	Full	5.0 v			1.3	μΛ
		$V_{I} = V + -5.5 V$		Full	3.6 V			3.4	μΑ



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## **ELECTRICAL CHARACTERISTICS FOR 5-V SUPPLY**<sup>(1)</sup>

 $V_{+} = 4.5 \text{ V}$  to 5.5 V,  $T_{A} = -40^{\circ}\text{C}$  to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST COND	TIONS	TA	V.	MIN	TYP	MAX	UNIT
Analog Switch		"							
Analog signal range	V <sub>COM</sub> , V <sub>NO</sub> , V <sub>NC</sub>					V <sub>+</sub> – 5.5		V+	V
ON-state		$V_{NC} \text{ or } V_{NO} = V_{+}, 1.6 \text{ V},$	COM to NO or	25°C			0.52	0.74	
resistance	r <sub>on</sub>	$V_{+} = -5.5 V,$ $I_{COM} = -100 mA,$	NC, See Figure 16	Full	4.5 V			0.83	Ω
ON-state			COM to NO or	25°C			0.04	0.23	
resistance match between channels	∆r <sub>on</sub>	$V_{NC}$ or $V_{NO} = 1.6$ V, $I_{COM} = -100$ mA,	NC, See Figure 16	Full	4.5 V			0.30	Ω
ON-state		$V_{\rm NC} \text{ or } V_{\rm NO} = V_+, 1.6 \text{ V},$	COM to NO or	25°C			0.076	0.46	_
resistance flatness	r <sub>on(flat)</sub>	$V_{+} = -5.5 V,$ $I_{COM} = -100 mA,$	NC, See Figure 16	Full	4.5 V			0.5	Ω
Shunt switch resistance (TS5A22364 only)	r <sub>SH</sub>	$I_{\rm NO}$ or $I_{\rm NC}$ = 10 mA		Full	4.5 V		16	36	Ω
		$V_{\rm NC} = 4.5 \text{ V}, \text{ V}_{+} - 5.5 \text{ V}$		25°C		-50		50	
NC, NO OFF leakage current	I <sub>NC(OFF)</sub> , I <sub>NO(OFF)</sub>	$\begin{array}{l} V_{COM} = V_{+} - 5.5 \ V, \ 4.5 \ V \\ V_{NO} = Open \\ COM \ to \ NO \\ or \\ V_{NO} = 4.5 \ V, \ V_{+} - 5.5 \ V, \\ V_{COM} = V_{+} - 5.5 \ V, \ 4.5 \ V \\ V_{NC} = Open \\ COM \ to \ NC \end{array}$	See Figure 17	Full	5.5 V	-375		375	nA
COM		$V_{NC}$ and $V_{NO}$ = Open,		25°C		-50		50	
ON leakage current	I <sub>COM(ON)</sub>	$V_{COM} = V_+, V_+ - 5.5 V_,$	See Figure 18	Full	5.5 V	-375		375	nA
<b>Digital Control In</b>	outs (IN) <sup>(2)</sup>								
Input logic high	VIH			Full		2.4		5.5	V
Input logic low	V <sub>IL</sub>			Full				0.8	V
Input leakage	կ <sub>H</sub> , կլ	$V_{IN} = V_{+} \text{ or } 0$		25°C	5.5 V	-250		250	nA
current	יH, יL			Full	0.0 V	-250		250	10.1

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

 (2) All unused digital inputs of the device must be held at V<sub>+</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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## **ELECTRICAL CHARACTERISTICS FOR 5-V SUPPLY (continued)**

 $V_{\star}$  = 4.5 V to 5.5 V,  $T_{A}$  = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CO	TA	۷.	MIN	TYP	MAX	UNIT	
Dynamic									
			0 05 5	25°C	5 V		27	80	
Turn-on time	t <sub>ON</sub>		C <sub>L</sub> = 35 pF, See Figure 20	Full	4.5 V to 5.5 V			80	ns
				25°C	5 V		13	70	
Turn-off time	t <sub>OFF</sub>	$R_{L} = 300 \Omega,$	$C_{\rm COM} = V_{+},$ $C_{\rm L} = 35 \ {\rm pF},$ $S_{\rm L} = 300 \ {\Omega},$ See Figure 20		4.5 V to 5.5 V			70	ns
Break-before- make time	t <sub>BBM</sub>		C <sub>L</sub> = 35 pF, See Figure 21	25°C	5 V	1	3.5		ns
Charge injection	Q <sub>C</sub>	$V_{GEN} = 0,$ $R_{GEN} = 0,$	C <sub>L</sub> = 1 nF, See Figure 26	25°C	5 V		10		рС
NC, NO OFF capacitance (TS5A22362 only)	C <sub>NC(OFF)</sub> , C <sub>NO(OFF)</sub>	$V_{NC}$ or $V_{NO} = V_+$ or $V_+ - 5.5 V_+$	See Figure 19	25°C	5 V		70		pF
NC, NO, COM ON capacitance	C <sub>COM(ON)</sub>	$V_{COM} = V_+ \text{ or GND},$	See Figure 19	25°C	5 V		370		pF
Digital input capacitance	CI	$V_1 = V_+$ or GND	See Figure 19	25°C	5 V		2.6		pF
Bandwidth	BW	R <sub>L</sub> = 50 Ω,	See Figure 21	25°C	5 V		18.3		MHz
OFF isolation	O <sub>ISO</sub>	$R_L = 50 \Omega$ ,	f = 100 kHz, See Figure 24	25°C	5 V		-70		dB
Crosstalk	X <sub>TALK</sub>	$R_L = 50 \Omega$ ,	f = 100 kHz, See Figure 25	25°C	5 V		-78		dB
Total harmonic distortion	THD	$R_{L} = 600 \Omega,$ $C_{L} = 15 \text{ pF},$	f = 20 Hz to 20 kHz, See Figure 27	25°C	5 V		0.009		%
Supply									
Positive supply current	I+	$V_{I} = V_{+}$ or GND		25°C			0.2	1.3	
				Full	5.5 V			3.5	μA
		$V_{I} = V_{+} - 5.5 V$	Full				5		



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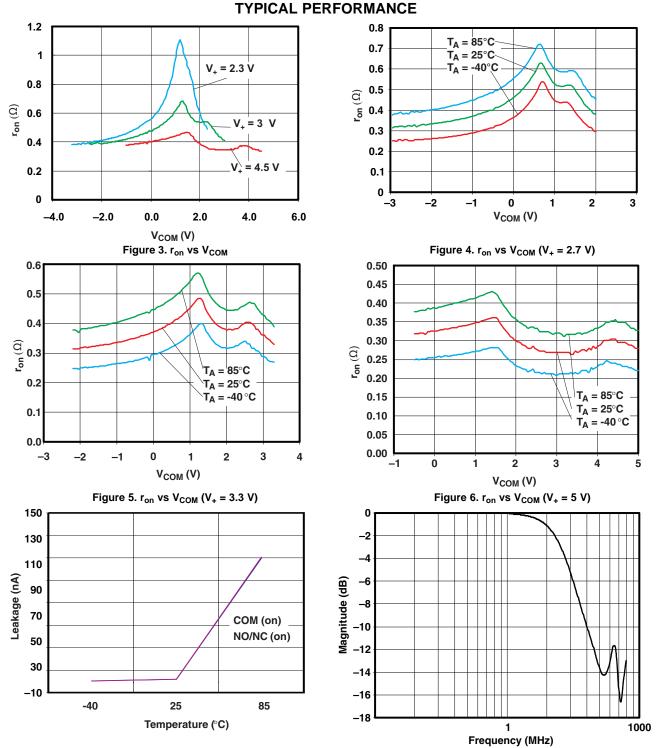
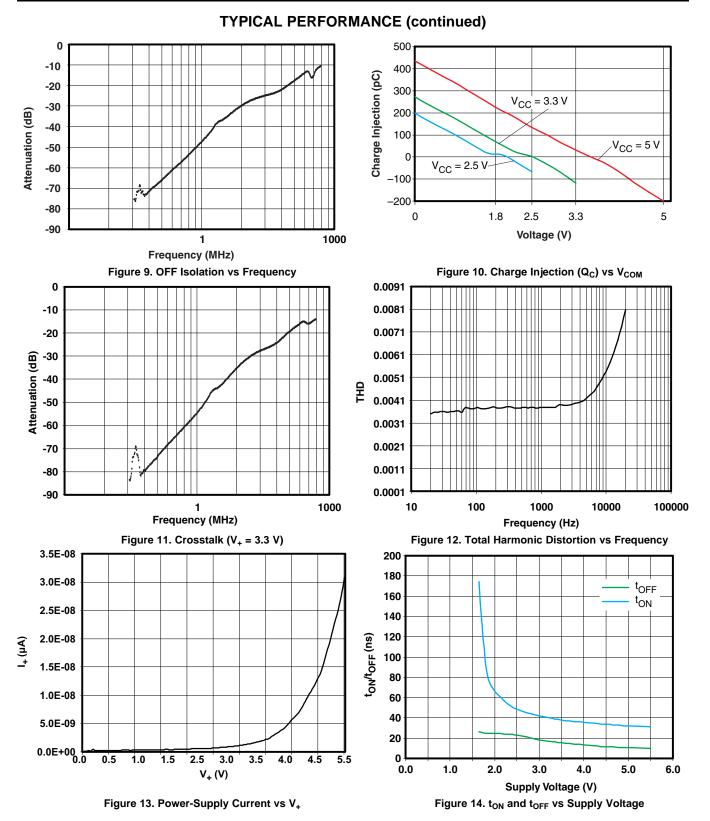


Figure 7. Leakage Current vs Temperature

Figure 8. Insertion Loss



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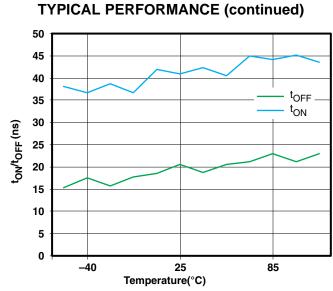


Figure 15.  $t_{\text{ON}}$  and  $t_{\text{OFF}}$  vs Temperature (2.5-V Supply)



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PARAMETER MEASUREMENT INFORMATION

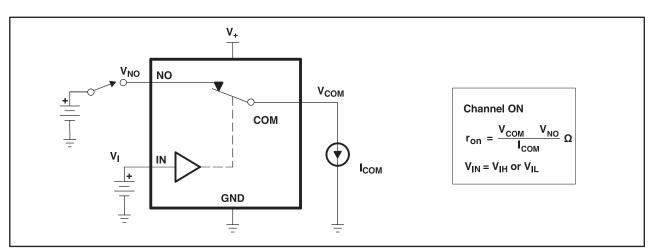
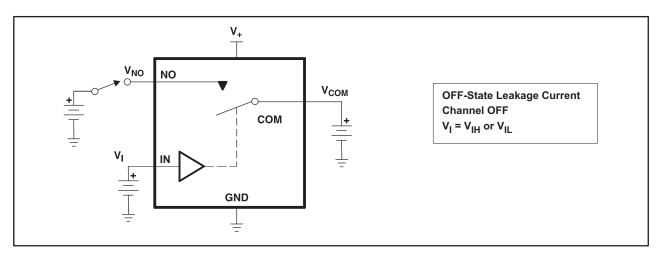
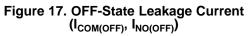


Figure 16. ON-State Resistance (ron)







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## PARAMETER MEASUREMENT INFORMATION (continued)

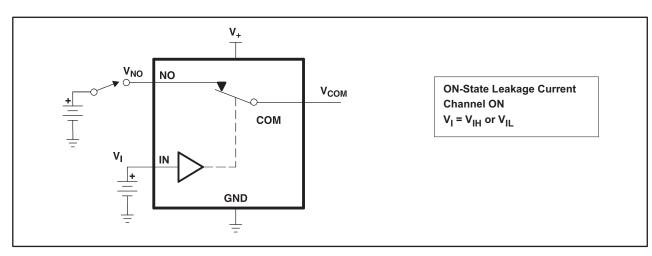
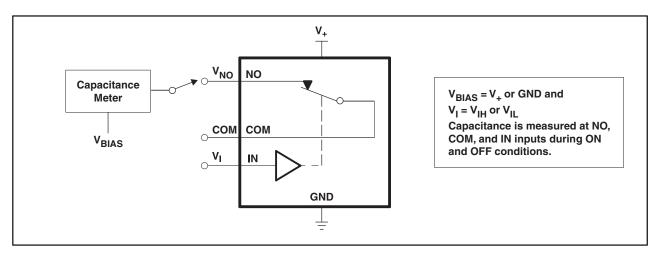
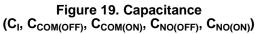


Figure 18. ON-State Leakage Current (I<sub>COM(ON)</sub>, I<sub>NO(ON)</sub>)

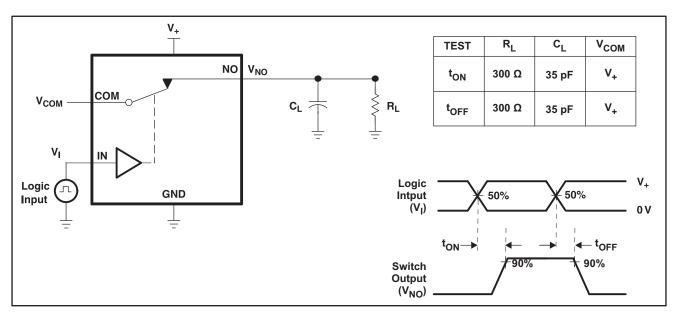




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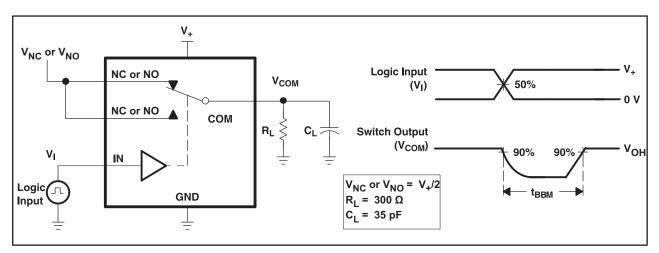


## PARAMETER MEASUREMENT INFORMATION (continued)

A. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>r</sub> < 5 ns, t<sub>f</sub> < 5 ns.

B. C<sub>L</sub> includes probe and jig capacitance.

## Figure 20. Turn-On (t<sub>ON</sub>) and Turn-Off Time (t<sub>OFF</sub>)



A.  $C_L$  includes probe and jig capacitance.

B. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>r</sub> < 5 ns, t<sub>f</sub> < 5 ns.

Figure 21. Break-Before-Make Time (t<sub>BBM</sub>) (TS5A22362 Only)



#### ۷+ V<sub>NC</sub> or V<sub>NO</sub> ٧. V<sub>+</sub> Logic Input NC or NO <br /> < V<sub>COM</sub> 50% (V<sub>I</sub>) 0 V NC or NO v<sub>он</sub> COM Ş $C_L$ Switch Output RL 10% 10% (V<sub>COM</sub>) 0 V ٧I IN $V_{NC}$ or $V_{NO}$ = GND R<sub>L</sub> = 1 kΩ Logic л t<sub>BBM</sub> GND Input R<sub>PU</sub> = 100 Ω Ŧ $C_L = 35 \, pF$

## PARAMETER MEASUREMENT INFORMATION (continued)

Figure 22. Break-Before-Make Time (t<sub>BBM</sub>) (TS5A22364 Only)

- A.  $C_L$  includes probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>r</sub> < 5 ns, t<sub>f</sub> < 5 ns.

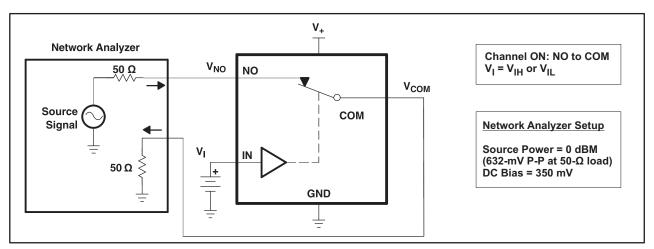
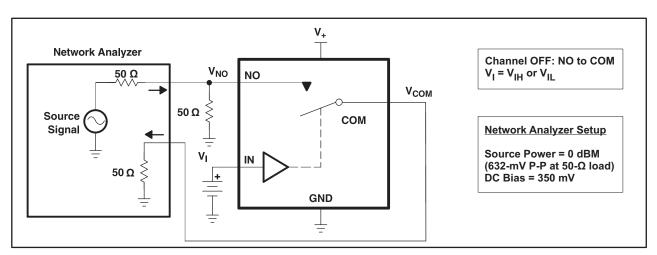


Figure 23. Bandwidth (BW)



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## PARAMETER MEASUREMENT INFORMATION (continued)

Figure 24. OFF Isolation (O<sub>ISO</sub>)

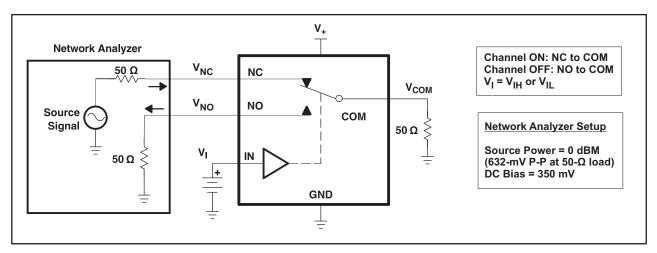
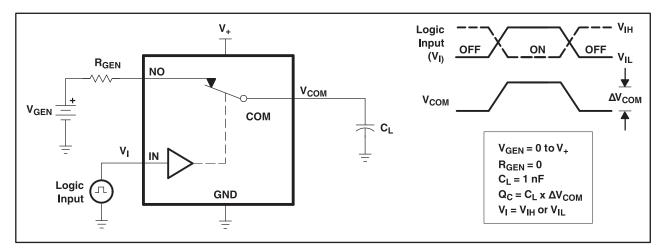


Figure 25. Crosstalk (X<sub>TALK</sub>)



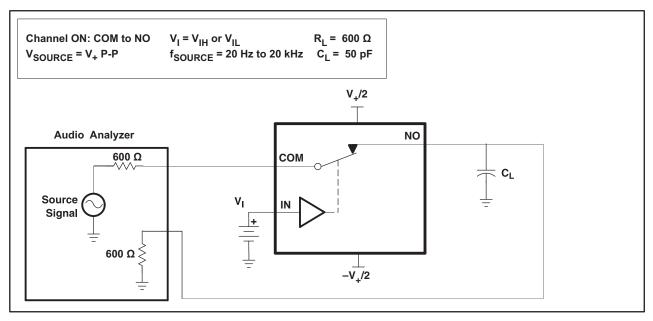
## PARAMETER MEASUREMENT INFORMATION (continued)



A. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>0</sub> = 50  $\Omega$ , t<sub>r</sub> < 5 ns, t<sub>f</sub> < 5 ns.

B. C<sub>L</sub> includes probe and jig capacitance.

### Figure 26. Charge Injection (Q<sub>C</sub>)



A. C<sub>L</sub> includes probe and jig capacitance.

### Figure 27. Total Harmonic Distortion (THD)



# PACKAGE OPTION ADDENDUM

15-Sep-2008

## **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TS5A22362DGSR	ACTIVE	MSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM
TS5A22362DGSRG4	ACTIVE	MSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM
TS5A22362DRCR	ACTIVE	SON	DRC	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TS5A22362DRCRG4	ACTIVE	SON	DRC	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TS5A22362YZPR	ACTIVE	DSBGA	YZP	10	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM
TS5A22364DGSR	ACTIVE	MSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5A22364DGSRG4	ACTIVE	MSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5A22364DRCR	ACTIVE	SON	DRC	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TS5A22364YZPR	ACTIVE	DSBGA	YZP	10	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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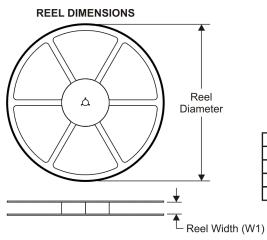
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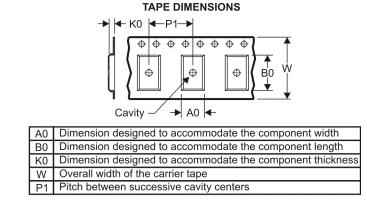


# PACKAGE MATERIALS INFORMATION

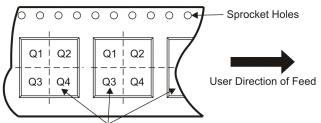
14-Aug-2008

## TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



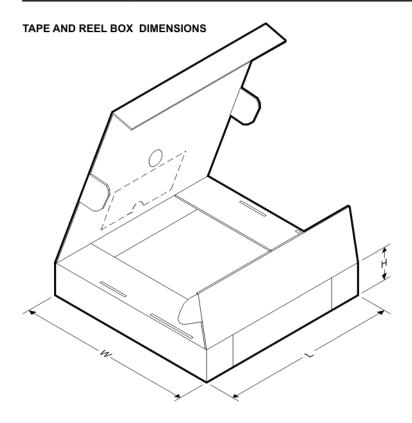


*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS5A22362DGSR	MSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TS5A22362DRCR	SON	DRC	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TS5A22364DGSR	MSOP	DGS	10	2500	330.0	13.0	5.3	3.4	1.4	8.0	12.0	Q1
TS5A22364DRCR	SON	DRC	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2



# PACKAGE MATERIALS INFORMATION

14-Aug-2008

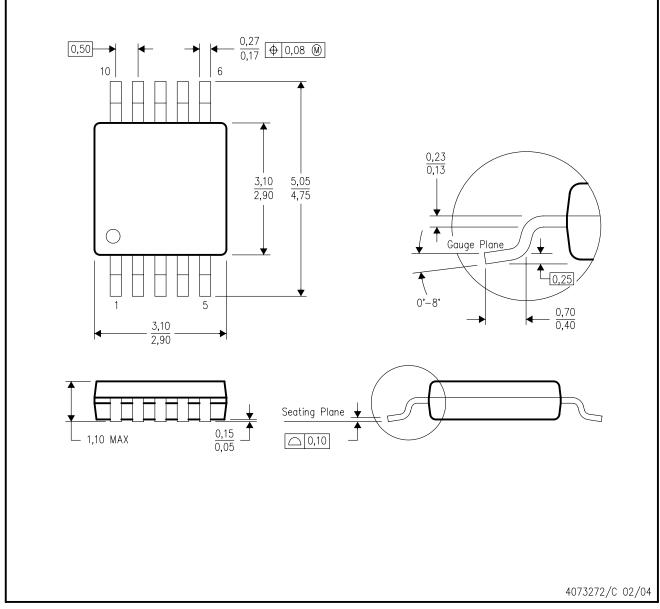


*All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS5A22362DGSR	MSOP	DGS	10	2500	358.0	335.0	35.0
TS5A22362DRCR	SON	DRC	10	3000	346.0	346.0	29.0
TS5A22364DGSR	MSOP	DGS	10	2500	358.0	335.0	35.0
TS5A22364DRCR	SON	DRC	10	3000	346.0	346.0	29.0

Pack Materials-Page 2

DGS (S-PDSO-G10)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-187 variation BA.



YZP (R-XBGA-N10) (CUSTOM) DIE-SIZE BALL GRID ARRAY 1,00 <u>1,40</u> 1,34 В 0,50 -А D ++ С ++<u>1,90</u> 1,84 1,50 0,25 В ++0,50 +А +1 3 2 Ball A3 Index Area Bottom View 10X  $\emptyset \frac{0,25}{0,21}$ ⊕ Ø 0,015 M C A B 1 \_\_\_\_ 0,05 C 0,50 Max Seating Plane C <u>0,19</u> 0,15 4204741-5/G 07/2008

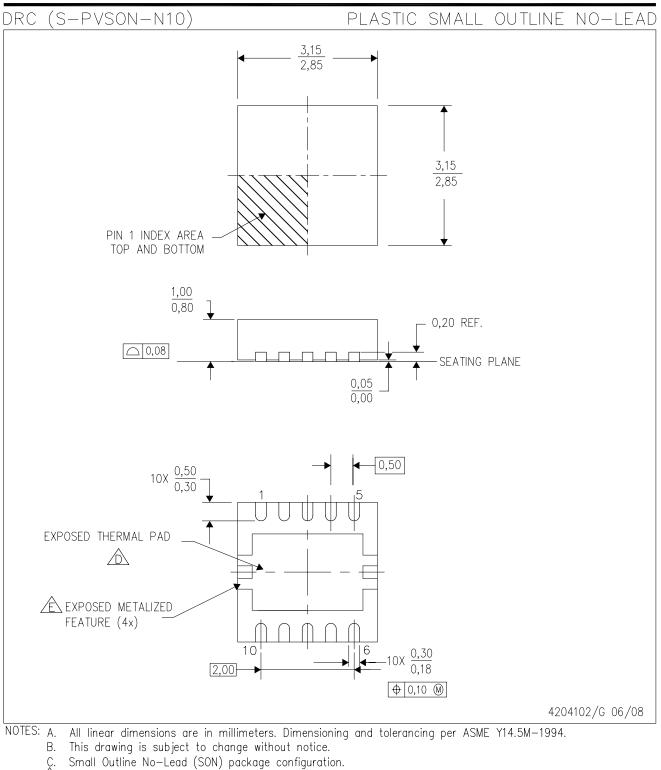
NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This package is a lead-free solder ball design.

#### NanoFree is a trademark of Texas Instruments.



## **MECHANICAL DATA**



- The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
- A Metalized features are supplier options and may not be on the package.



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## THERMAL PAD MECHANICAL DATA

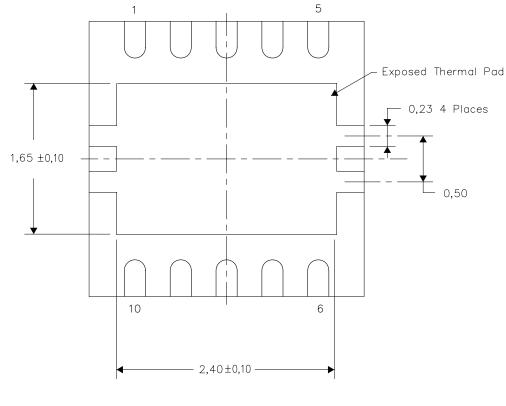
DRC (S-PVSON-N10)

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, Quad Flatpack No-Lead Logic Packages, Texas Instruments Literature No. SCBA017. This document is available at www.ti.com.

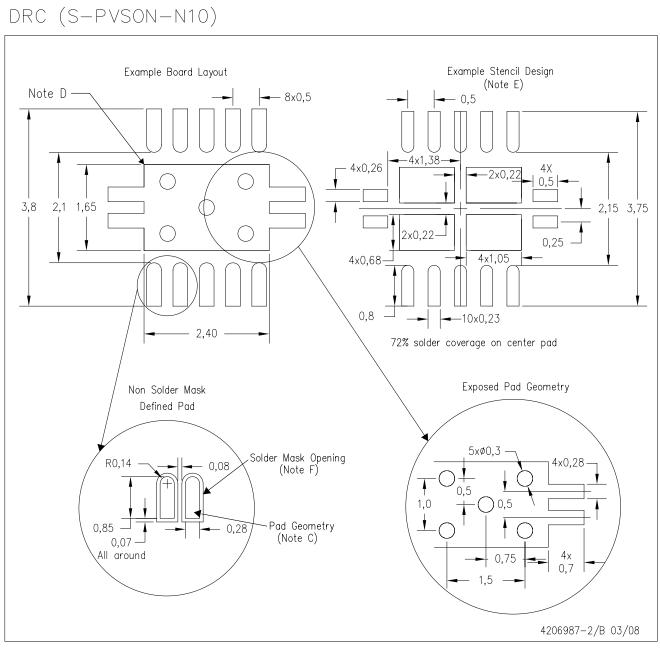
The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

NOTE: All linear dimensions are in millimeters





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.

D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SCBA017, SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="http://www.ti.com">http://www.ti.com</a>.

- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



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